

High voltage fast-switching NPN power transistor

Features

- High voltage capability
- Minimum lot-to-lot spread for reliable operation
- Very high switching speed

Applications

- Electronic ballast for fluorescent lighting
- Flyback and forward single transistor low power converters

Description

The device is manufactured using high voltage multi-epitaxial planar technology for high switching speeds and medium voltage capability.

It uses a cellular emitter structure with planar edge termination to enhance switching speeds while maintaining the wide RBSOA.

The device is designed for use in lighting applications and low cost switch-mode power supplies.

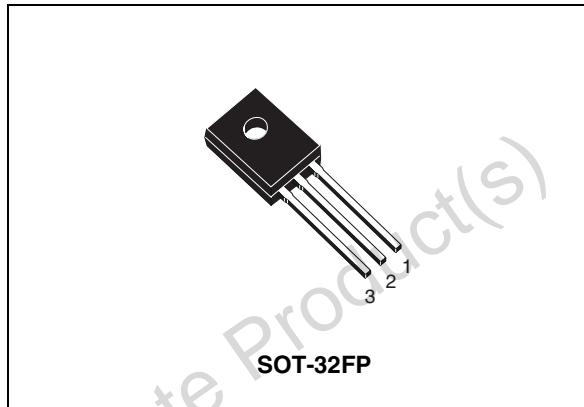


Figure 1. Internal schematic diagram

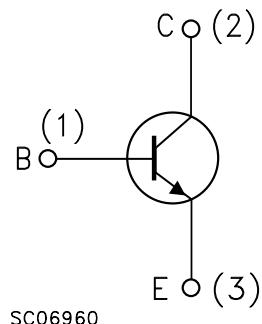


Table 1. Device summary

Order code	Marking	Package	Packaging
STT13005FP	T13005FP	SOT-32FP	Bag

1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{CES}	Collector-emitter voltage ($V_{BE} = 0$)	700	V
V_{CEO}	Collector-emitter voltage ($I_B = 0$)	400	V
V_{EBO}	Emitter-base voltage ($I_C = 0$)	9	V
I_C	Collector current	2	A
I_{CM}	Collector peak current ($t_P < 5$ ms)	4	A
I_B	Base current	1	A
I_{BM}	Base peak current ($t_P < 5$ ms)	2	A
P_{tot}	Total dissipation at $T_c = 25$ °C	30	W
T_{stg}	Storage temperature	-65 to 150	°C
T_J	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R_{thJC}	Thermal resistance junction-case max	4.2	°C/W

2 Electrical characteristics

$T_{case} = 25^\circ\text{C}$ unless otherwise specified.

Table 4. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
I_{CES}	Collector cut-off current ($V_{BE} = 0$)	$V_{CE} = 700 \text{ V}$ $V_{CE} = 700 \text{ V} \quad T_C = 125^\circ\text{C}$			100 500	μA μA
I_{CEO}	Collector cut-off current ($I_B = 0$)	$V_{CE} = 400 \text{ V}$			250	μA
V_{EBO}	Emitter-base voltage ($I_C = 0$)	$I_E = 10 \text{ mA}$	9			V
$V_{CEO(sus)}$ ⁽¹⁾	Collector-emitter sustaining voltage ($I_B = 0$)	$I_C = 10 \text{ mA}$	400			V
$V_{CE(sat)}$ ⁽¹⁾	Collector-emitter saturation voltage	$I_C = 0.5 \text{ A} \quad I_B = 125 \text{ mA}$			0.5	V
		$I_C = 0.8 \text{ A} \quad I_B = 0.2 \text{ A}$			1	V
		$I_C = 1.6 \text{ A} \quad I_B = 0.4 \text{ A}$			1.5	V
$V_{BE(sat)}$ ⁽¹⁾	Base-emitter saturation voltage	$I_C = 0.5 \text{ A} \quad I_B = 125 \text{ mA}$			1	V
		$I_C = 0.8 \text{ A} \quad I_B = 0.2 \text{ A}$			1.3	V
		$I_C = 1.6 \text{ A} \quad I_B = 0.4 \text{ A}$			1.5	V
h_{FE} ⁽¹⁾	DC current gain	$I_C = 0.5 \text{ A} \quad V_{CE} = 5 \text{ V}$ $I_C = 2 \text{ A} \quad V_{CE} = 5 \text{ V}$	10 8		50	
t_r t_s t_f	Resistive load Rise time Storage time Fall time	$I_C = 1 \text{ A} \quad V_{CC} = 125 \text{ V}$ $I_{B1} = -I_{B2} = 0.2 \text{ A}$		0.4 3.2 0.25	0.7 4.5 0.4	μs μs μs
t_s t_f	Inductive load Storage time Fall time	$I_C = 1 \text{ A} \quad I_{B1} = 0.2 \text{ A}$ $V_{BE(off)} = -5 \text{ V} \quad L = 50 \text{ mH}$ $V_{Clamp} = 300 \text{ V}$		0.8 0.16		μs μs

1. Pulse test: pulse duration $\leq 300 \mu\text{s}$, duty cycle $\leq 2\%$

2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

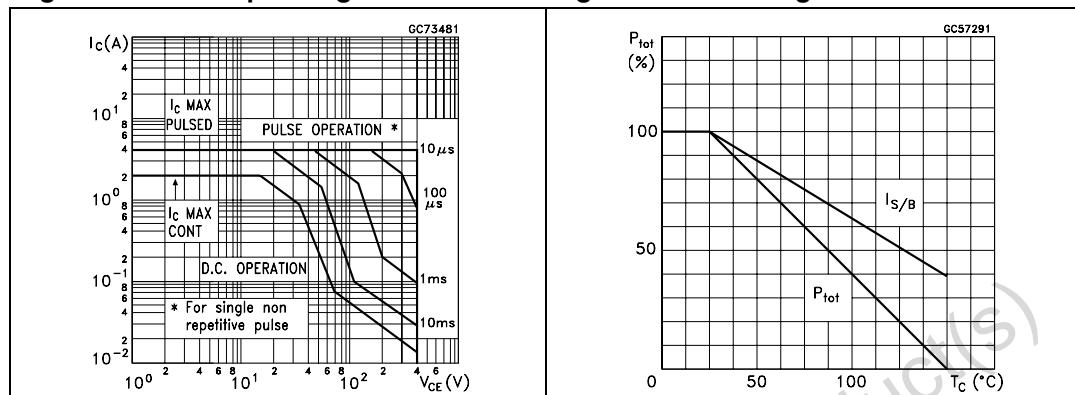


Figure 3. Derating curve

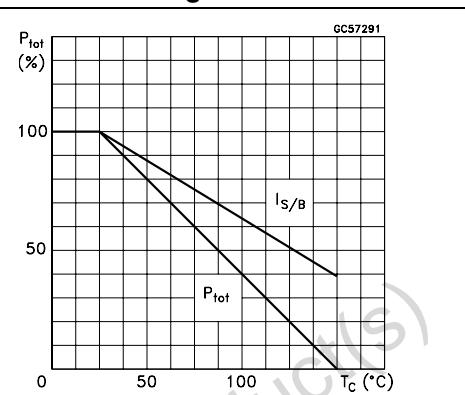


Figure 4. DC current gain ($V_{CE} = 1$ V)

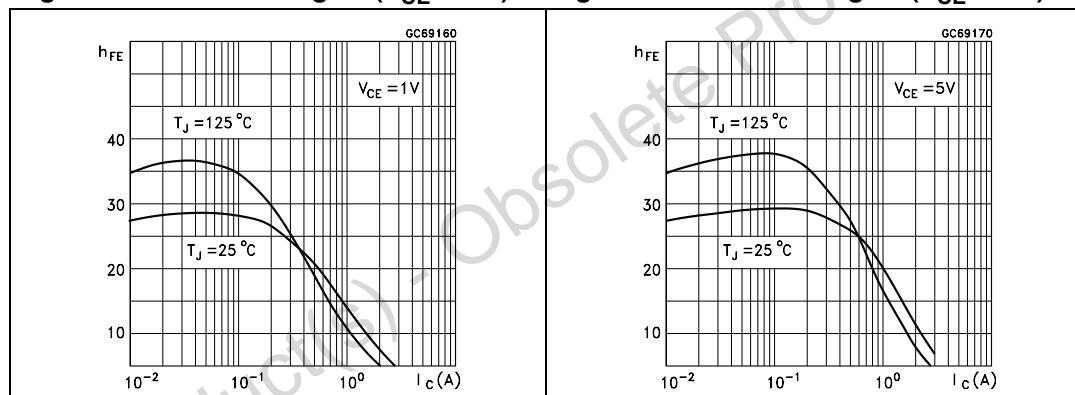


Figure 5. DC current gain ($V_{CE} = 5$ V)

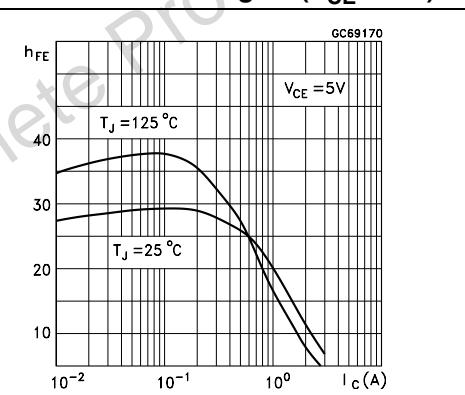


Figure 6. Collector-emitter saturation voltage

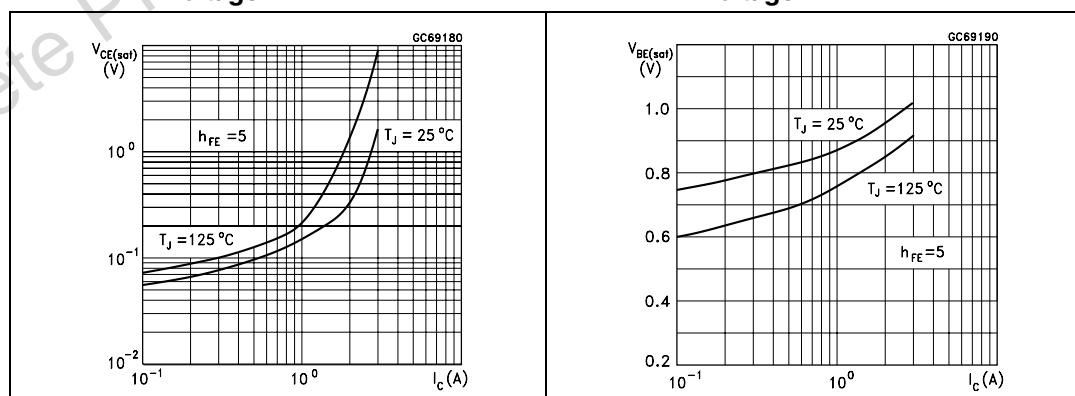


Figure 7. Base-emitter saturation voltage

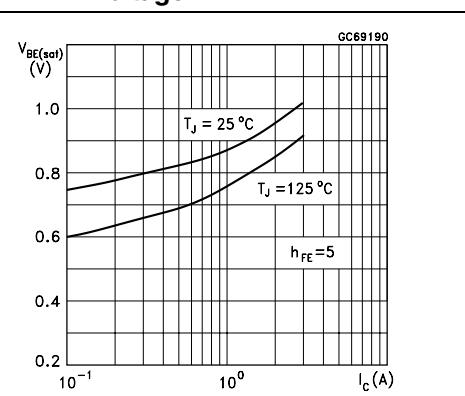
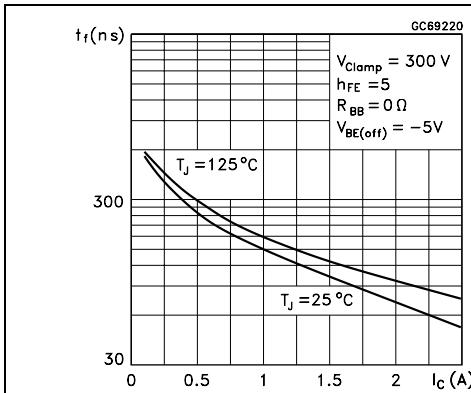
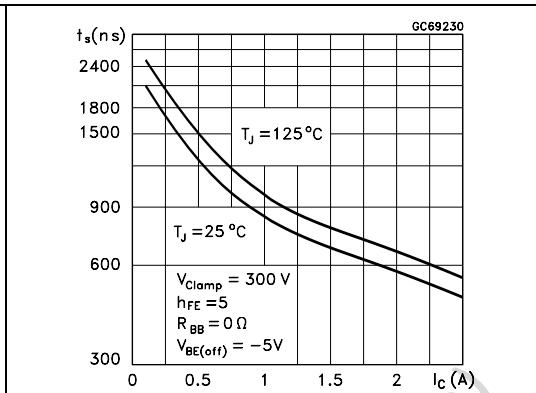
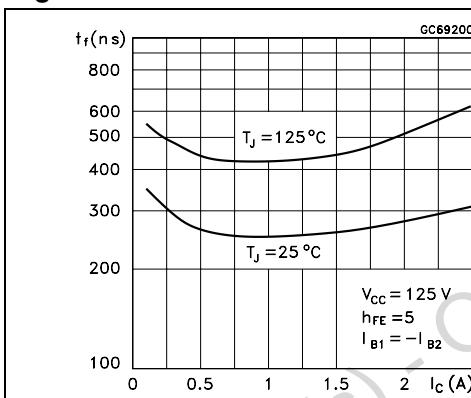
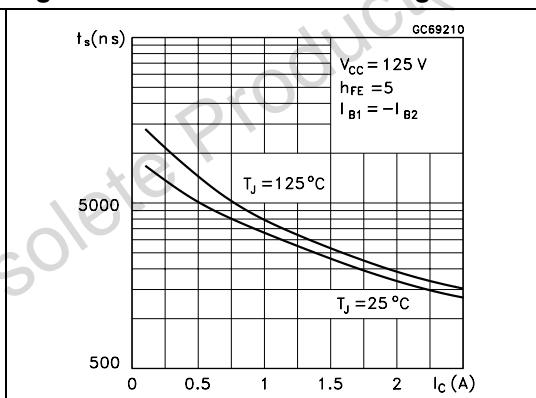
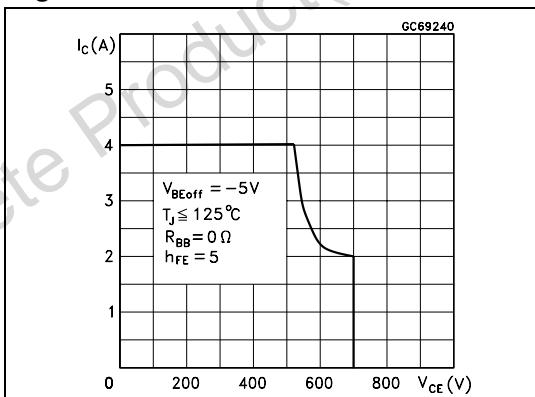
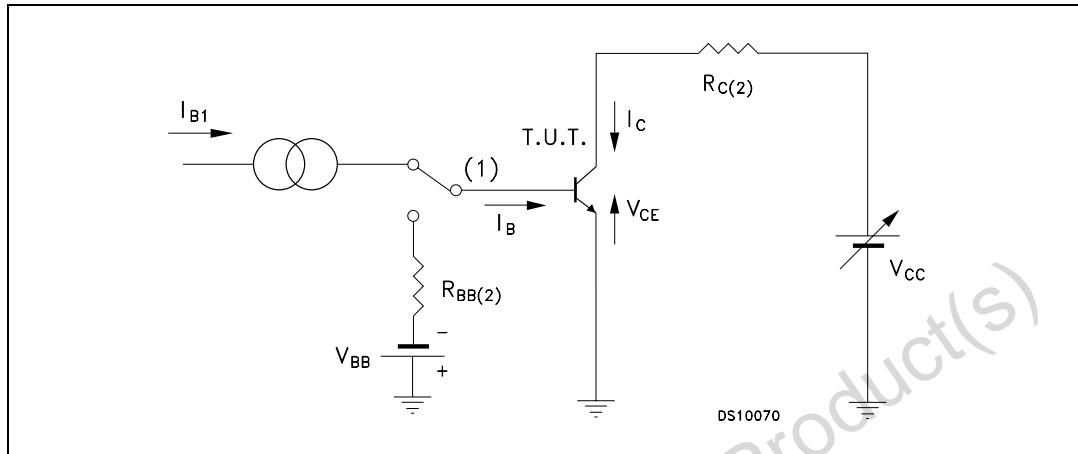


Figure 8. Inductive load fall time**Figure 9. Inductive load storage time****Figure 10. Resistive load fall time****Figure 11. Resistive load storage time****Figure 12. Reverse biased SOA**

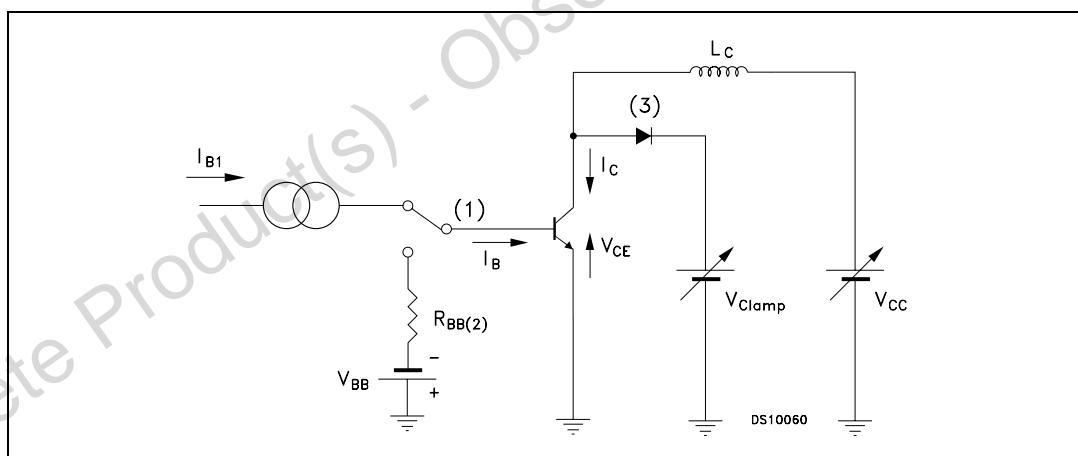
2.2 Test circuits

Figure 13. Resistive load switching test circuit



1. Fast electronic switch
2. Non-inductive resistor

Figure 14. Inductive load switching test circuit



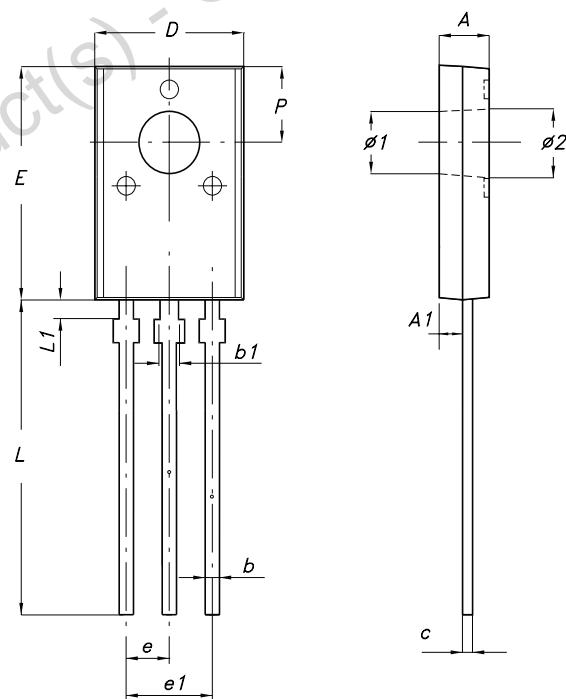
1. Fast electronic switch
2. Non-inductive resistor
3. Fast recovery rectifier

3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com.
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SOT-32FP mechanical data

DIM.	mm.		
	MIN.	TYP	MAX.
A	3.00		3.40
A1	1.80		2.20
b	0.66		0.86
b1	1.17		1.37
c	0.45		0.60
D	7.80		8.20
E	10.80		11.20
e		2.28	
e1	4.46		4.66
L	15.30		15.70
L1	1.30		1.50
P	4.04		4.24
ø1	2.90		3.10
ø2	3.10		3.30



4 Revision history

Table 5. Document revision history

Date	Revision	Changes
06-May-2009	1	Initial release
10-Sep-2009	2	Document status promoted from preliminary data to datasheet

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